

# SGM48754 Quad SPST CMOS Analog Switch

### **GENERAL DESCRIPTION**

The SGM48754 is a CMOS analog switch configured as quad SPST. This CMOS device can operate from 2.5V to 5.5V single supplies. Each switch can handle rail-to-rail analog signals. The off-leakage current is only 1nA (TYP) at  $+25^{\circ}$ C.

All digital inputs can support 1.8V logic control I/O.

The SGM48754 is available in Green SOIC-14 and TSSOP-14 packages. It operates over an ambient temperature range of -40°C to +85°C.

### **FEATURES**

- Guaranteed On-Resistance 24Ω (TYP) with +5V Supply
- Guaranteed On-Resistance Match Between Channels
- "T" Type Switch
- Low Off-Leakage Current 1nA (TYP) at +25°C
- Low On-Leakage Current 1nA (TYP) at +25°C
- Optimized Rise Time and Fall Time of A, B, C and D Control Pins to Reduce Clock Feedthrough Effect
- 2.5V to 5.5V Single-Supply Operation
- 1.8V Logic Compatible
- Low Distortion: 0.35% ( $R_L = 600\Omega$ , f = 20Hz to 20kHz)
- High Off-Isolation: -80dB ( $R_L = 50\Omega$ , f = 1MHz)
- -40°C to +85°C Operating Temperature Range
- Available in Green SOIC-14 and TSSOP-14 Packages

## **APPLICATIONS**

Battery-Operated Equipment Audio and Video Signal Routing Low-Voltage Data-Acquisition Systems Communications Circuits Automotive



### PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
00140754	SOIC-14	-40°C to +85°C	SGM48754YS14G/TR	SGM48754YS14 XXXXX	Tape and Reel, 2500
SGM48754	TSSOP-14	-40°C to +85°C	SGM48754YTS14G/TR	SGM48754 YTS14 XXXXX	Tape and Reel, 4000

NOTE: XXXXX = Date Code and Vendor Code.

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

#### **ABSOLUTE MAXIMUM RATINGS**

V <sub>CC</sub> to GND	0.3V to 6V
Voltage into Any Terminal <sup>(1)</sup> 0.3	V to (V <sub>CC</sub> + 0.3V)
Continuous Current into Any Terminal	±20mA
Peak Current	
(Pulsed at 1ms, 10% duty cycle)	±40mA
Junction Temperature	150°C
Storage Temperature Range	65℃ to +150℃
Lead Temperature (Soldering, 10s)	260°C
ESD Susceptibility	
HBM	4000V
MM	300V

#### NOTE:

1. Voltages exceeding  $V_{CC}$  or GND on any signal terminal are clamped by internal diodes. Limit forward-diode current to maximum current rating.

#### **RECOMMENDED OPERATING CONDITIONS**

Supply Voltage Range	2.5V to 5.5V
Operating Temperature Range	40°C to +85°C

#### **OVERSTRESS CAUTION**

Stresses beyond those listed may cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational section of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

#### **ESD SENSITIVITY CAUTION**

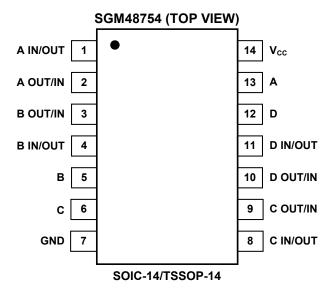
This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time.



## **PIN CONFIGURATIONS**



### **PIN DESCRIPTION**

PIN	NAME	FUNCTION
1	A IN/OUT	Switch A Input/Output.
2	A OUT/IN	Switch A Input/Output.
3	B OUT/IN	Switch B Input/Output.
4	B IN/OUT	Switch B Input/Output.
5	В	Switch B Control.
6	С	Switch C Control.
7	GND	Ground.
8	C IN/OUT	Switch C Input/Output.
9	C OUT/IN	Switch C Input/Output.
10	D OUT/IN	Switch D Input/Output.
11	D IN/OUT	Switch D Input/Output.
12	D	Switch D Control.
13	A	Switch A Control.
14	V <sub>CC</sub>	Power Supply.

## **FUNCTION TABLE**

SELECT INPUTS	SWITCH STATUS			
A/B/C/D	SWITCH STATUS			
High	All Switches Close			
Low	All Switches Open			

NOTE: Input and output pins are identical and interchangeable. Any may be considered an input or output; signals pass equally well in both directions.



# **ELECTRICAL CHARACTERISTICS**

 $(V_{CC} = 5.0V, Full = -40^{\circ}C \text{ to } +85^{\circ}C, x = A, B, C \text{ and } D \text{ switch in/out or out/in, typical values are at } T_A = +25^{\circ}C, \text{ unless otherwise}$ noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
ANALOG SWITCH					•		•
Analog Signal Range	V <sub>X_</sub> , V <sub>X</sub>		Full	GND		V <sub>CC</sub>	V
On-Resistance	Davi	$1/1 = 501/1 = 1m^{1}$	+25°C		24	30	Ω
OII-Resistance	R <sub>ON</sub>	$\begin{array}{c} \mbox{Full} \\ V_{CC} = 5.0V, I_X = 1mA & \begin{array}{c} +25^{\circ} \\ \hline Ful \\ +25^{\circ} \\ \hline Ful \\ V_{CC} = 5.0V, I_X = 1mA & \begin{array}{c} +25^{\circ} \\ \hline Ful \\ V_{CC} = 5.0V, V_X = 4.5V \mbox{ or } 0V, \\ V_X = 4.5V \mbox{ or } 0V & \\ V_{CC} = 5.0V, V_X = 4.5V \mbox{ or } 0V, \\ V_X = 4.5V \mbox{ or } 0V & \\ V_{CC} = 5.0V, V_X = 4.5V \mbox{ or } 0V & \\ V_X = 5.0V, V_X = 5.0V, V_X = 5.0V, Test \mbox{ circuit } 1 & \\ V_X = 0V, f = 1MHz, Test \mbox{ circuit } 3 & \\ V_X = 0V, f = 1MHz, Test \mbox{ circuit } 3 & \\ V_X = 0V, f = 1MHz, Test \mbox{ circuit } 4 & \\ V_X = 5.0\Omega & \\ F_X = 5.00 & \\ F_X = $	Full			35	12
On-Resistance Match	$\Delta R_{ON}$	$V_{00} = 5.0 V_{10} = 1 m A_{10}$	+25°C		1	2.6	Ω
Between Channels	Δηση		Full			3	- 12
On-Resistance Flatness	R <sub>FLAT(ON)</sub>	$V_{00} = 5.0 V I_{V} = 1 m \Delta$	+25°C	Full       GND       V <sub>CC</sub> $25^{\circ}C$ 24       30         Full       35 $25^{\circ}C$ 1       2.6         Full       3 $25^{\circ}C$ 8       11         Full       3 $25^{\circ}C$ 8       11         Full       1       1000 $25^{\circ}C$ 1       1000 $25^{\circ}C$ 1       1000 $25^{\circ}C$ 1       1000 $25^{\circ}C$ 1.7       1000 $25^{\circ}C$ 1.7       0.5 $25^{\circ}C$ 1       100 $25^{\circ}C$ 1       1 $25^{\circ}C$ 100       1 $25^{\circ}C$ 9       1 $25^{\circ}C$ 9       1 $25^{\circ}C$ 9       1 $25^{\circ}C$ 9       1 $25^{\circ}C$ 18       1 $25^{\circ}C$ <t< td=""><td>Ω</td></t<>	Ω		
	TELAT(ON)		Full			14	32
X_Off Leakage Current	$I_{X_{OFF}}$	$V_{CC} = 5.0V, V_{X_{-}} = 4.5V \text{ or } 0V,$ $V_{X} = 4.5V \text{ or } 0V$	+25°C		1	1000	nA
X Off Leakage Current	$I_{X(OFF)}$		+25°C		1	1000	nA
X On Leakage Current	I <sub>X(ON)</sub>	$V_{CC} = 5.0V, V_X = 4.5V \text{ or } 0V$	+25°C		1	1000	nA
DIGITAL I/O	•		-				
Logic Input Logic Threshold High	V <sub>AH</sub> , V <sub>BH</sub> , V <sub>CH</sub> ,V <sub>DH</sub>		+25°C	1.7			V
Logic Input Logic Threshold Low	$\begin{matrix} V_{AL},  V_{BL},  V_{CL,} \\ V_{DL} \end{matrix}$		+25°C			0.5	V
Input-Current High	I <sub>AH</sub> , I <sub>BH</sub> , I <sub>CH,</sub> I <sub>DH</sub>	$V_A, V_B, V_C, V_D = V_{CC}$	+25°C		1		nA
Input-Current Low	$I_{AL},I_{BL},I_{CL},I_{DL}$	$V_A$ , $V_B$ , $V_C$ , $V_D = 0V$	+25°C		1		nA
DYNAMIC CHARACTERIST	ICS						-
Turn-On Time	t <sub>ON</sub>	$V_{X}, V_{Y} = 3V, R_L = 300\Omega, C_L = 35pF,$ Test Circuit 1	+25°C		40		ns
Turn-Off Time	t <sub>OFF</sub>	$V_{X}, V_{Y} = 3V, R_L = 300\Omega, C_L = 35pF,$ Test Circuit 1	+25°C		100		ns
Input Transition Rise or Fall Rate	Δt/ΔV		+25°C			20	ns/V
Charge Injection	Q	$R_S = 0\Omega$ , C = 1nF, V <sub>S</sub> = 0V, Test Circuit 2	+25°C		7		рС
Input Off-Capacitance	CX_(OFF)	$V_{X_{-}} = 0V$ , f = 1MHz, Test Circuit 3	+25°C		9		pF
Output Off-Capacitance	C <sub>X(OFF)</sub>	V <sub>X</sub> = 0V, f = 1MHz, Test Circuit 3	+25°C		9		pF
Output On-Capacitance	C <sub>X(ON)</sub>	$V_{X_{-}} = 0V$ , f = 1MHz, Test Circuit 3	+25°C		18		pF
Off Isolation	O <sub>ISO</sub>	$R_L = 50\Omega$ , f = 1MHz, Test Circuit 4	+25°C		-80		dB
Crosstalk	X <sub>TALK</sub>	f = 1MHz, Test Circuit 4	+25°C		-95		dB
-3dB Bandwidth	BW	R <sub>L</sub> = 50Ω	+25°C		180		MHz
Total Harmonic Distortion	THD	$R_{L} = 600\Omega$ , $5V_{P-P}$ , f = 20Hz to 20kHz	+25°C		0.35		%
POWER SUPPLY		1	1		1		I.
Power Supply Range	Vcc		Full	2.5		5.5	V
Power Supply Current	I <sub>CC</sub>	$V_{CC} = 5.0V, V_A, V_B, V_C, V_D = V_{CC} \text{ or } 0$	+25°C		0.001	6	μA



# **ELECTRICAL CHARACTERISTICS**

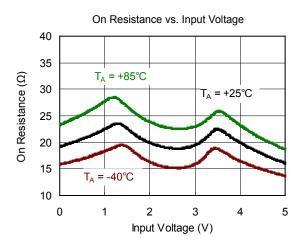
(V<sub>CC</sub> = 3.3V, Full = -40°C to +85°C, x = A, B, C and D switch in/out or out/in, typical values are at  $T_A$  = +25°C, unless otherwise noted.)

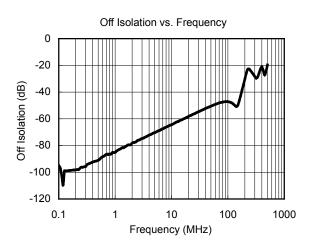
PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
ANALOG SWITCH	•		_				
Analog Signal Range	V <sub>X_</sub> , V <sub>X</sub>		Full	GND		Vcc	V
On-Resistance	Ron	lx = 1mA	+25°C		40	55	Ω
On-Resistance	RON		Full			58	12
Off Leakage Current	I <sub>X_(OFF)</sub>	V <sub>X</sub> _ = 1V, 3V, V <sub>X</sub> = 3V, 1V	+25°C		1	1000	nA
Off Leakage Current	I <sub>X(OFF)</sub>	V <sub>X</sub> _ = 1V, 3V, V <sub>X</sub> = 3V, 1V	+25°C		1	1000	nA
On Leakage Current	I <sub>X(ON)</sub>	V <sub>X</sub> = 3V, 1V	+25°C		1	1000	nA
DIGITAL I/O					•		
Logic Input Logic Threshold High	V <sub>AH</sub> , V <sub>BH</sub> , V <sub>CH</sub> , V <sub>DH</sub>		+25°C	1.7			V
Logic Input Logic Threshold Low	V <sub>AL</sub> , V <sub>BL</sub> , V <sub>CL</sub> , V <sub>DL</sub>		+25°C			0.5	V
Input-Current High	I <sub>AH</sub> , I <sub>BH</sub> , I <sub>CH</sub> I <sub>DH</sub>	$V_A$ , $V_B$ , $V_C$ , $V_D = V_{CC}$	+25°C		1		nA
Input-Current Low	I <sub>AL</sub> , I <sub>BL</sub> , I <sub>CL</sub> I <sub>DL</sub>	$V_A$ , $V_B$ , $V_C$ , $V_D = 0V$	+25°C		1		nA
DYNAMIC CHARACTERIST	ICS						
Turn-On Time	t <sub>ON</sub>	$V_{X}$ , $V_{Y}$ = 3V, $R_L$ = 300 $\Omega$ , $C_L$ = 35pF, Test Circuit 1	+25°C		75		ns
Turn-Off Time	toff	$V_{X}, V_{Y}$ = 3V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, Test Circuit 1	+25°C		125		ns
Input Transition Rise or Fall Rate	Δt/ΔV		+25°C			100	ns/V
-3dB Bandwidth	BW	$R_L = 50\Omega$	+25°C		180		MHz
Charge Injection	Q	$R_S = 0\Omega$ , C = 1nF, V <sub>S</sub> = 0V, Test Circuit 2	+25°C		3.5		рС
POWER SUPPLY	•	·			•		
Power Supply Current	I <sub>CC</sub>	$V_A$ , $V_B$ , $V_C$ , $V_D = V_{CC}$ or 0	+25°C		0.001	3	μA



### **TYPICAL PERFORMANCE CHARACTERISTICS**

 $V_{CC}$  = 5.0V, unless otherwise noted.

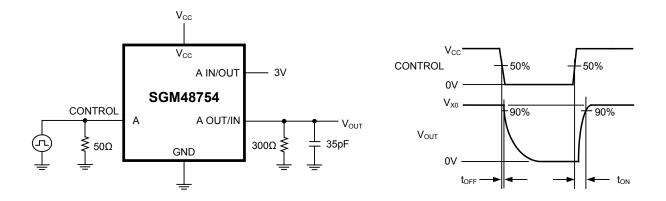




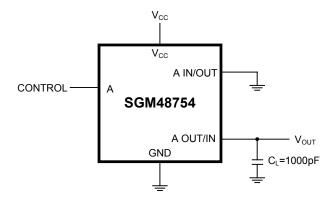


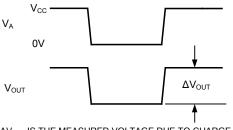
### SGM48754

## **TEST CIRCUITS**



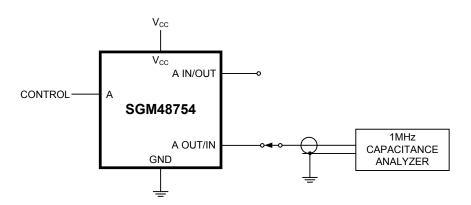
Test Circuit 1. Switching Times (ton, toff)

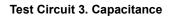




 $\Delta V_{OUT}$  IS THE MEASURED VOLTAGE DUE TO CHARGE TRANSFER ERROR Q WHEN THE CHANNEL TURNS OFF. Q =  $\Delta V_{OUT}$  × CL



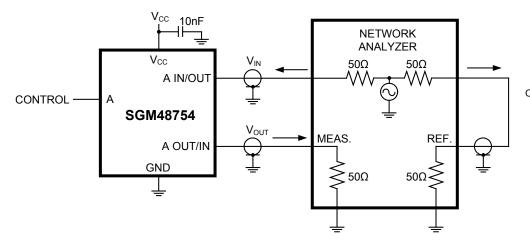






### SGM48754

## **TEST CIRCUITS**



$$\label{eq:off-isolation} \begin{split} & \mathsf{OFF}\text{-}\mathsf{ISOLATION} = 20\mathsf{log}\;(\mathsf{V}_\mathsf{OUT}/\mathsf{V}_\mathsf{IN})\\ & \mathsf{ON}\text{-}\mathsf{LOSS} = 20\mathsf{log}\;(\mathsf{V}_\mathsf{OUT}/\mathsf{V}_\mathsf{IN})\\ & \mathsf{CROSSTALK} = 20\mathsf{log}\;(\mathsf{V}_\mathsf{OUT}/\mathsf{V}_\mathsf{IN}) \end{split}$$

MEASUREMENTS ARE STANDARDIZED AGAINST SHORT AT SOCKET TERMINALS. OFF-ISOLATION IS MEASURED BETWEEN COM AND "OFF" NO TERMINAL ON EACH SWITCH. ON-LOSS IS MEASURED BETWEEN COM AND "ON" NO TERMINAL ON EACH SWITCH. CROSSTALK IS MEASURED FROM ONE CHANNEL (A, B, C, D) TO ALL OTHER CHANNELS. SIGNAL DIRECTION THROUGH SWITCH IS REVERSED; WORST VALUES ARE RECORDED.

Test Circuit 4. Off Isolation, On Loss and Crosstalk



## **APPLICATION INFORMATION**

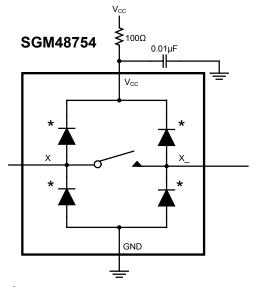
#### Power-Supply Considerations Overview

The SGM48754 construction is typical of most CMOS analog switch. It supports single power supply.  $V_{CC}$  and GND are used to drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD protection diodes are internally connected between each analog-signal pin and both  $V_{CC}$  and GND. If any analog signal exceeds  $V_{CC}$  or GND, one of these diodes will conduct. During normal operation, these and other reverse-biased ESD diodes leak, forming the only current drawn from  $V_{CC}$  or GND.

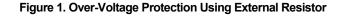
Virtually all the analog leakage current comes from the ESD diodes. Although the ESD diodes on a given signal pin are identical and therefore fairly well balanced, they are reverse biased differently. Each is biased by either  $V_{CC}$  or GND and the analog signal. This means their leakages will vary as the signal varies. The difference in the two diode leakages to the  $V_{CC}$  and GND pins constitutes the analog-signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of either the same or opposite polarity.

#### **Over-Voltage Protection**

Proper power-supply sequencing is recommended for the CMOS device. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence  $V_{CC}$  on first, followed by the logic inputs and analog signals. If power-supply sequencing is not possible, add one 100 $\Omega$  resistor in series with the supply  $V_{CC}$  pin for over-voltage protection (Figure 1).



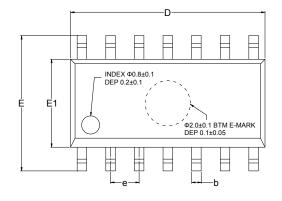
\*INTERNAL PROTECTION DIODES

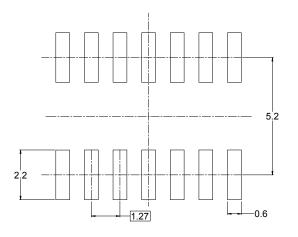




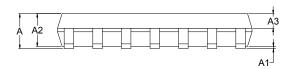
## PACKAGE OUTLINE DIMENSIONS

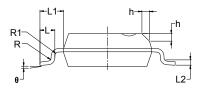
SOIC-14





#### RECOMMENDED LAND PATTERN (Unit: mm)



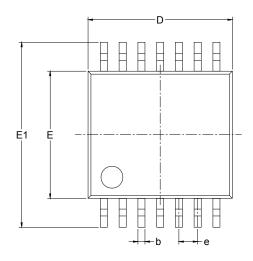


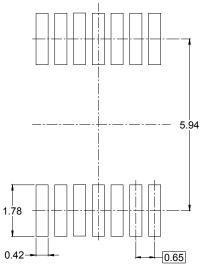
Symbol	Dimens	sions In Mill	imeters	Dimensions In Inches			
Symbol	MIN	MOD	MAX	MIN	MOD	MAX	
A	1.35		1.75	0.053		0.069	
A1	0.10		0.25	0.004		0.010	
A2	1.25		1.65	0.049		0.065	
A3	0.55		0.75	0.022		0.030	
b	0.36		0.49	0.014		0.019	
D	8.53		8.73	0.336		0.344	
E	5.80		6.20	0.228		0.244	
E1	3.80		4.00	0.150		0.157	
е		1.27 BSC			0.050 BSC		
L	0.45		0.80	0.018		0.032	
L1		1.04 REF			0.040 REF		
L2		0.25 BSC			0.01 BSC		
R	0.07			0.003			
R1	0.07			0.003			
h	0.30		0.50	0.012		0.020	
θ	0°		8°	0°		8°	



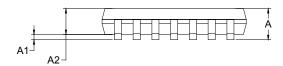
## PACKAGE OUTLINE DIMENSIONS

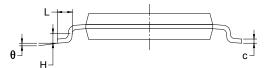
### **TSSOP-14**





RECOMMENDED LAND PATTERN (Unit: mm)



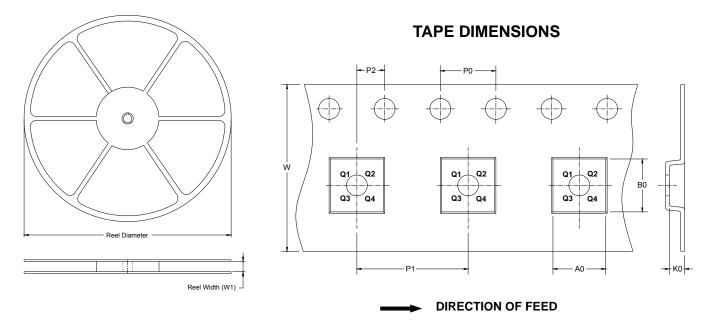


Symbol		nsions meters	Dimensions In Inches			
2	MIN	MAX	MIN	MAX		
A		1.200		0.047		
A1	0.050	0.150	0.002	0.006		
A2	0.800	1.050	0.031	0.041		
b	0.190	0.300	0.007	0.012		
С	0.090	0.200	0.004	0.008		
D	4.860	5.100	0.191	0.201		
E	4.300	4.500	0.169	0.177		
E1	6.250	6.550	0.246	0.258		
е	0.650	BSC	0.026	BSC		
L	0.500	0.700	0.02	0.028		
Н	0.25	TYP	0.01	TYP		
θ	1°	7°	1°	7°		



## TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**



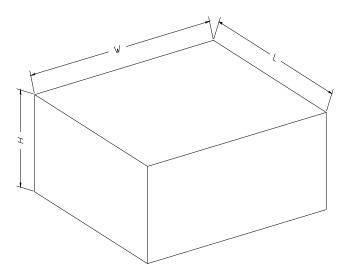
NOTE: The picture is only for reference. Please make the object as the standard.

### **KEY PARAMETER LIST OF TAPE AND REEL**

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC-14	13″	16.4	6.6	9.3	2.1	4.0	8.0	2.0	16.0	Q1
TSSOP-14	13″	12.4	6.95	5.6	1.2	4.0	8.0	2.0	12.0	Q1



#### **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

### **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
13″	386	280	370	5	DD0002

